

Application serial no.: 10/0
Inventor: Hawley et al.
Docket No.: ACT-307DVA
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Filed: December 28, 2001
Title: Method for Fabricating a MOS Transistor Having Implant Total Radiation...
Attorney: Kenneth D'Alessandro
Sierra Patent Group, Ltd.

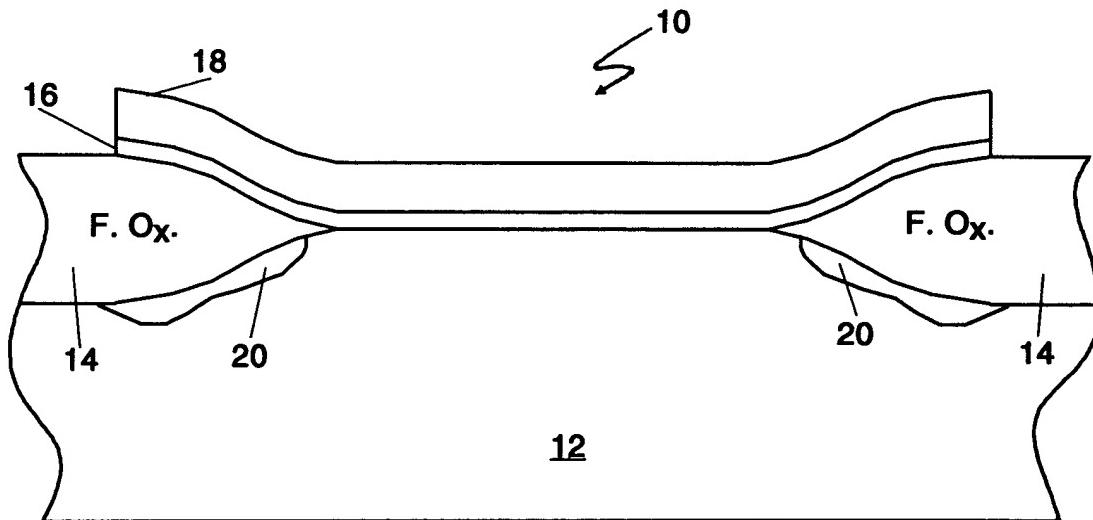


FIG. 1
Prior Art

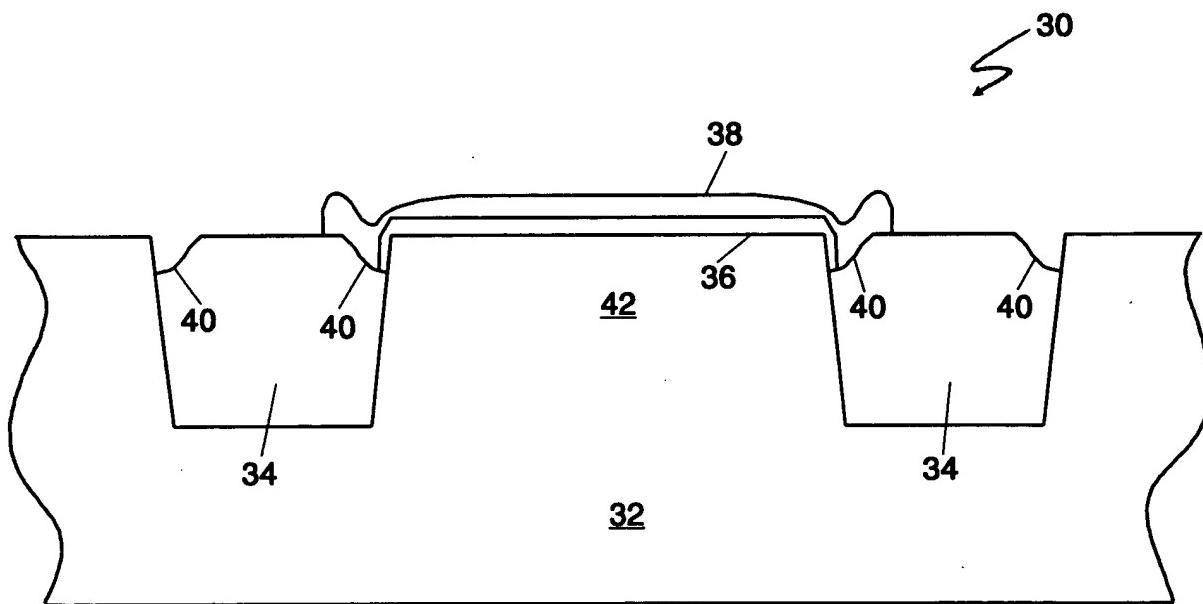


FIG. 2
Prior Art

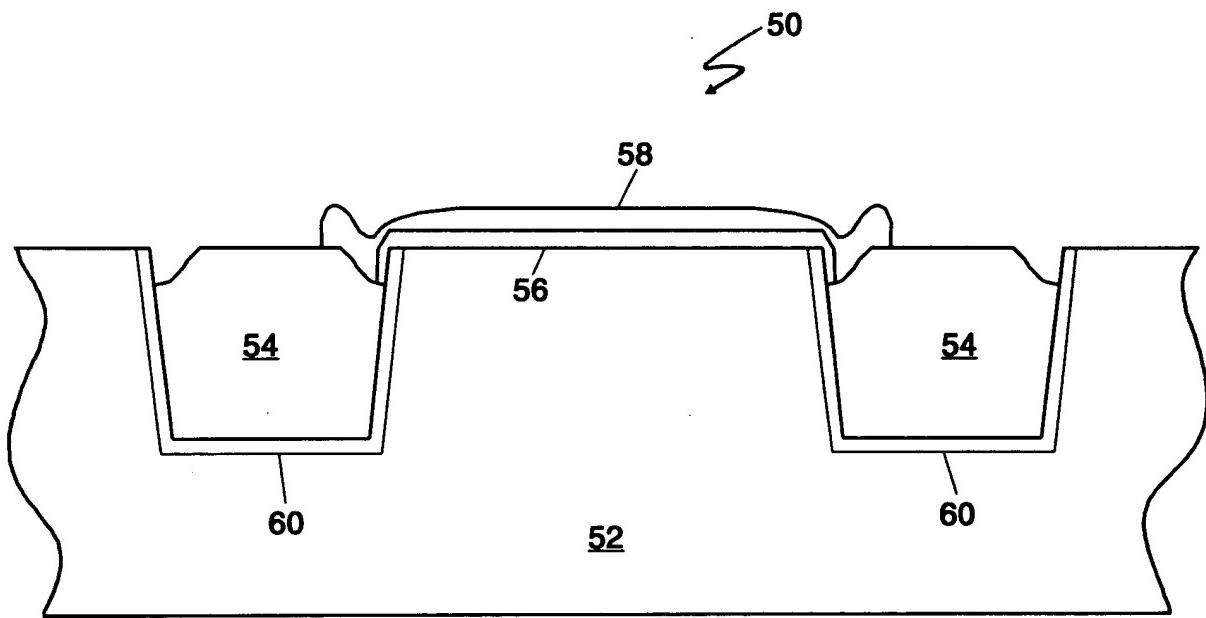


FIG. 3

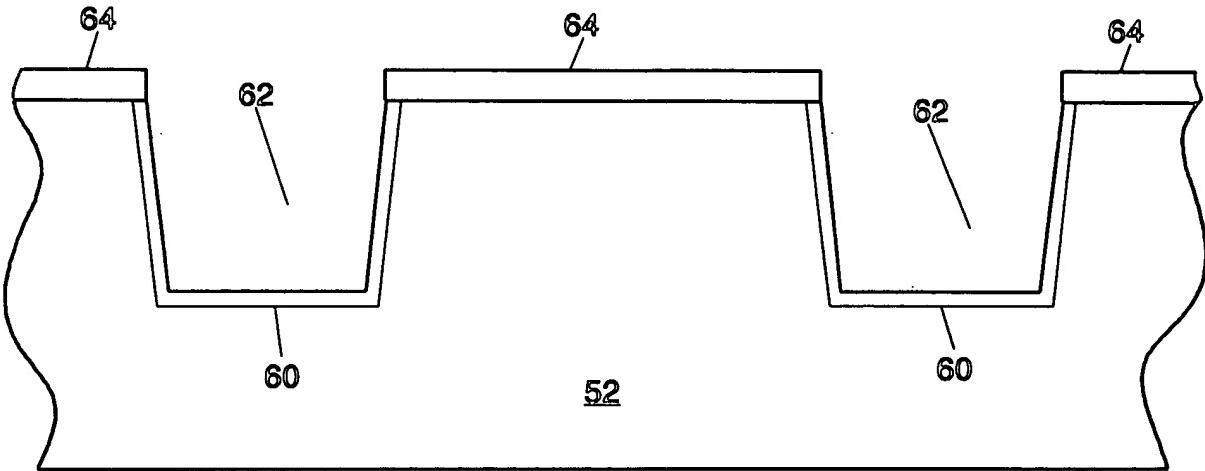


FIG. 4A

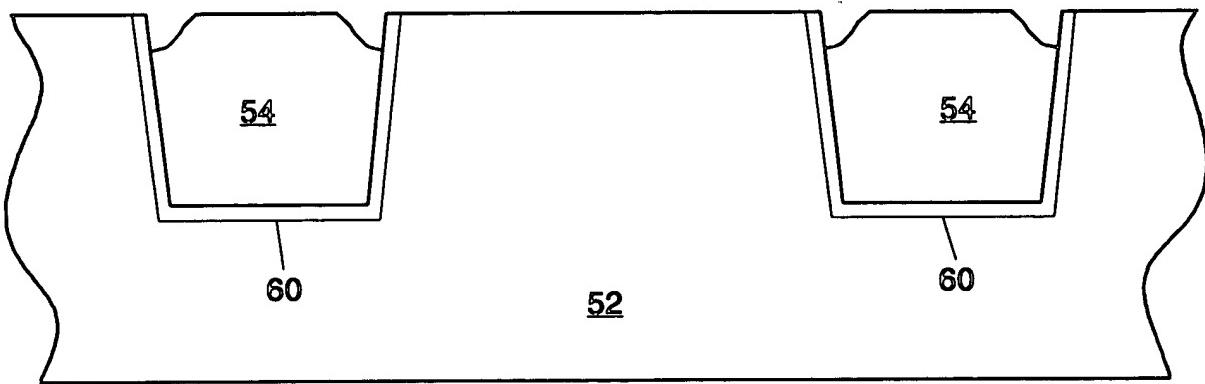


FIG. 4B

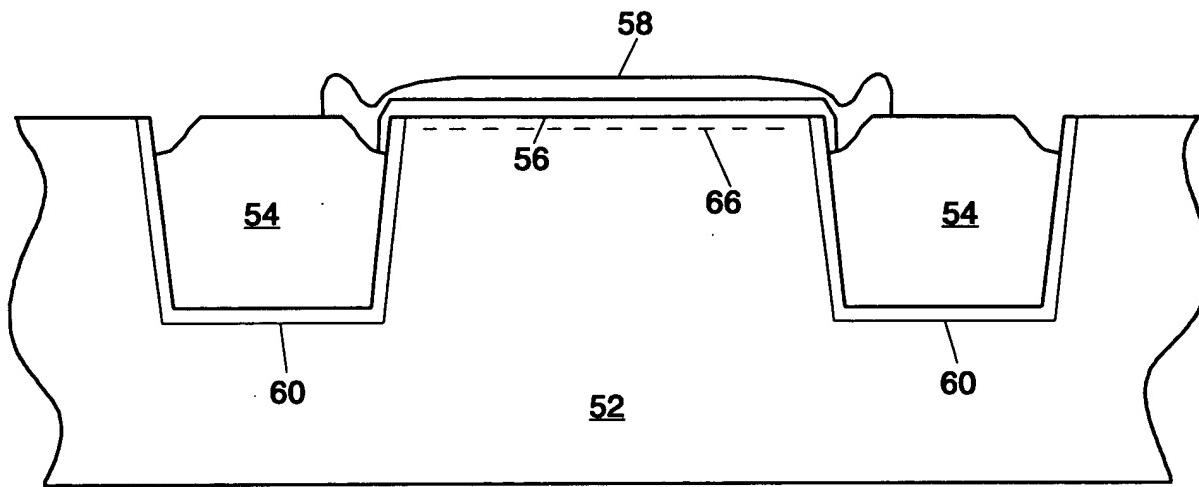


FIG. 4C